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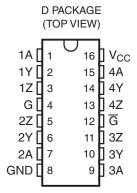
# LOW-VOLTAGE HIGH-SPEED QUADRUPLE DIFFERENTIAL LINE DRIVER WITH ±15-kV IEC ESD PROTECTION

#### **FEATURES**

- Meets or Exceeds Standards TIA/EIA-422-B and ITU Recommendation V.11
- Operates From a Single 3.3-V Power Supply
- ESD Protection for RS422 Bus Pins
  - ±15-kV Human-Body Model (HBM)
  - ±8-kV IEC61000-4-2, Contact Discharge
  - ±15-kV IEC61000-4-2, Air-Gap Discharge
- Switching Rates up to 32 MHz
- Propagation Delay Time . . . 8 ns Typ
- Pulse Skew Time . . . 500 ps Typ
- High Output-Drive Current . . . ±30 mA
- Controlled Rise and Fall Times . . . 5 ns Typ
- Differential Output Voltage With 100-Ω Load . . . 2.6 V Typ
- Accepts 5-V Logic Inputs With 3.3-V Supply
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Driver Output Short-Protection Circuit
- Glitch-Free Power-Up/Power-Down Protection

# SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Extended (-55°C/105°C)
   Temperature Range<sup>(1)</sup>
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability



(1) Additional temperature ranges are available - contact factory

#### DESCRIPTION/ORDERING INFORMATION

The AM26LV31E is a quadruple differential line driver with 3-state outputs. This driver has ±15-kV ESD (HBM and IEC61000-4-2, Air-Gap Discharge) and ±8-kV ESD (IEC61000-4-2, Contact Discharge) protection. This device is designed to meet TIA/EIA-422-B and ITU Recommendation V.11 drivers with reduced supply voltage.

The device is optimized for balanced-bus transmission at switching rates up to 32 MHz. The outputs have high current capability for driving balanced lines, such as twisted-pair transmission lines, and provide a high impedance in the power-off condition.

The AM26LV31ES is characterized for operation from -55°C to 105°C.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
-55°C to 105°C	SOIC - D	Tape and reel	AM26LV31ESDREP	A26LV31ESP	

<sup>(1)</sup> Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

<sup>(2)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

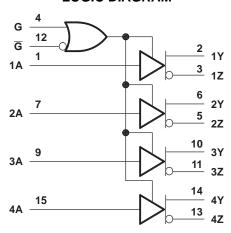


#### **FUNCTION TABLE**(1)

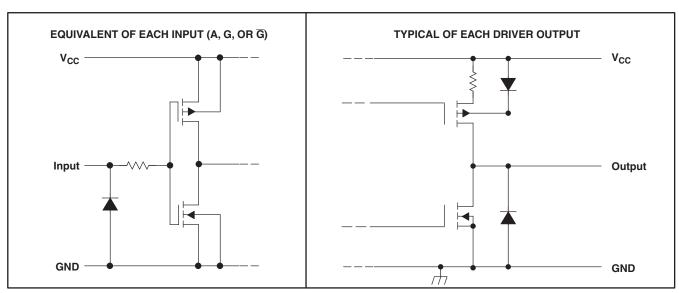
INPUT	ENA	BLES	OUTPUTS		
Α	G	G	Y	Z	
Н	Н	Х	Н	L	
L	Н	Χ	L	Н	
Н	Χ	L	Н	L	
L	Χ	L	L	Н	
X	L	Н	Z	Z	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)

#### **LOGIC DIAGRAM**



#### **SCHEMATIC**





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### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
$V_{CC}$	Supply voltage range (2)				6	V
VI	Input voltage range			-0.5	6	V
Vo	Output voltage range			-0.5	6	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0			-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0			-20	mA
lo	Continuous output current			±150	mA	
	Continuous current through V <sub>CC</sub> or	GND			±200	mA
TJ	Operating virtual junction temperatu	re			150	°C
$\theta_{JA}$	Package thermal impedance (3)(4)				73	°C/W
T <sub>A</sub>	Operating free-air temperature rang	Э		-55	105	°C
T <sub>stg</sub>	Storage temperature range			-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values except differential input voltage are with respect to the network GND. Maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . Selecting the maximum of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.



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#### RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage	3	3.3	3.6	V
VI	Input voltage	0		5.5	V
$V_{IH}$	High-level input voltage	2			V
$V_{IL}$	Low-level input voltage			0.8	V
I <sub>OH</sub>	High-level output current			-30	mA
I <sub>OL</sub>	Low-level output current			30	mA
T <sub>A</sub>	Operating free-air temperature	<b>-</b> 55		105	°C

#### **ELECTRICAL CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
$V_{OH}$	High-level output voltage	$V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OH} = -20 \text{ mA}$	2.4	3		V
V <sub>OL</sub>	Low-level output voltage	V <sub>IH</sub> = 2 V, V <sub>IL</sub> = 0.8 V, I <sub>OL</sub> = 20 mA		0.2	0.4	V
V <sub>OD1</sub>	Differential output voltage	$I_O = 0 \text{ mA}$	2		4	V
V <sub>OD2</sub>	Differential output voltage	$R_L = 100 \Omega \text{ (see Figure 1)}^{(2)}$	2	2.6		V
$\Delta  V_{OD} $	Change in magnitude of differential output voltage	$R_L = 100 \Omega \text{ (see Figure 1)}^{(2)}$			±0.4	V
V <sub>OC</sub>	Common-mode output voltage	$R_L = 100 \Omega \text{ (see Figure 1)}^{(2)}$		1.5	2	V
Δ V <sub>OC</sub>	Change in magnitude of common-mode output voltage	$R_L = 100 \Omega \text{ (see Figure 1)}^{(2)}$			±0.4	V
I <sub>O(OFF)</sub>	Output current with power off	$V_{CC} = 0$ , $V_{O} = -0.25$ V or 5.5 V			±127	μΑ
I <sub>OZ</sub>	High-impedance state output current	$V_{O} = -0.25 \text{ V or } 5.5 \text{ V}, G = 0.8 \text{ V or } \overline{G} = 2 \text{ V}$			±127	μΑ
I	Input current	V <sub>CC</sub> = 0 or 3.6 V, V <sub>I</sub> = 0 or 5.5 V			±10	μΑ
Ios	Short-circuit output current	$V_O = V_{CC}$ or $GND^{(3)}$	-30		-150	mA
I <sub>CC</sub>	Supply current (total package)	V <sub>I</sub> = V <sub>CC</sub> or GND, No load, enable			100	μΑ
C <sub>pd</sub>	Power dissipation capacitance	No load <sup>(4)</sup>		160		pF

All typical values are at  $V_{CC}=3.3~V,~T_A=25^{\circ}C.$  Refer to TIA-EIA-422-B for exact conditions. Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.  $C_{pd}$  determines the no-load dynamic current consumption:  $I_S=C_{pd}~\times~V_{CC}~\times~f+I_{CC}$ 



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#### **SWITCHING CHARACTERISTICS**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
t <sub>PHL</sub>	Propagation delay time, high- to low-level output	See Figure 2	4	8	12	ns
t <sub>PLH</sub>	Propagation delay time, low- to high-level output	See Figure 2	3.5	8	12	ns
t <sub>t</sub>	Transition time (t <sub>r</sub> or t <sub>f</sub> )	See Figure 2		5	10	ns
t <sub>PZH</sub>	Output-enable time to high level	See Figure 3		10	20	ns
t <sub>PZL</sub>	Output-enable time to low level	See Figure 4		10	20	ns
t <sub>PHZ</sub>	Output-disable time from high level	See Figure 3		10	20	ns
t <sub>PLZ</sub>	Output-disable time from low level	See Figure 4		10	20	ns
t <sub>sk(p)</sub>	Pulse skew			0.5	3	ns
t <sub>sk(o)</sub>	Skew limit (pin to pin)	See Figure 2 <sup>(2)(3)</sup>			1.5	ns
t <sub>sk(lim)</sub>	Skew limit (device to device)				3	ns
f <sub>(max)</sub>	Maximum operating frequency	See Figure 2		32		MHz

#### **ESD PROTECTION**

PARAMETER	TYP	UNIT	
	НВМ	±15	
Driver output	IEC61000-4-2, Air-Gap Discharge	±15	kV
	IEC61000-4-2, Contact Discharge	±8	

 <sup>(1)</sup> All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.
 (2) Pulse skew is defined as the |t<sub>PLH</sub> - t<sub>PHL</sub>| of each channel of the same device.
 (3) Skew limit (device to device) is the maximum difference in propagation delay times between any two channels of any two devices.

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#### PARAMETER MEASUREMENT INFORMATION

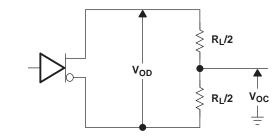
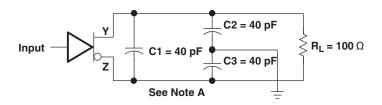
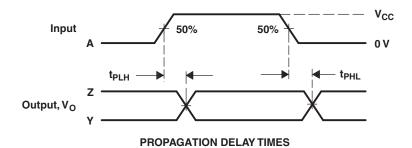
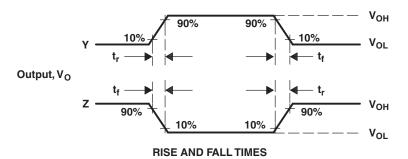


Figure 1. Test Circuit, V<sub>OD</sub> and V<sub>OC</sub>







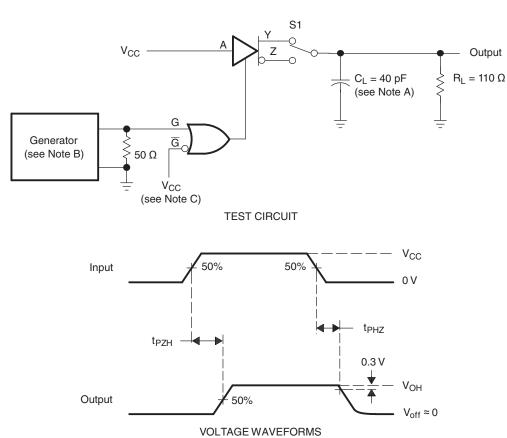
NOTES: A.  $C_L$  includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR = 32 MHz, 50% duty cycle,  $t_r$  and  $t_f \le 2$  ns.

Figure 2. Test Circuit and Voltage Waveforms, t<sub>PHL</sub> and t<sub>PLH</sub>

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#### PARAMETER MEASUREMENT INFORMATION (continued)

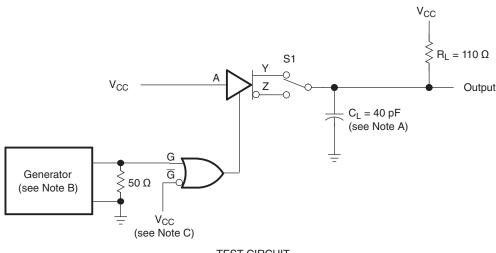


- A.  $C_L$  includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 10 MHz, duty cycle = 50%,  $t_r = t_f \le 2ns$ .
- C. To test the active-low enable  $\overline{G}$ , ground G and apply an inverted waveform  $\overline{G}$ .

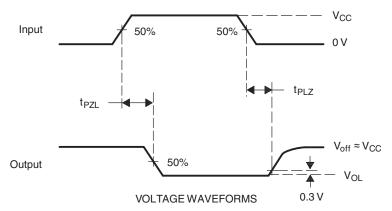
Figure 3. Test Circuit and Voltage Waveforms,  $t_{\text{PZH}}$  and  $t_{\text{PHZ}}$ 



#### PARAMETER MEASUREMENT INFORMATION (continued)



**TEST CIRCUIT** 



- A. C<sub>L</sub> includes probe and jig capacitance.
- The input pulse is supplied by a generator having the following characteristics: PRR = 10 MHz, duty cycle = 50%,  $t_r = t_f \le 2ns$ .
- C. To test the active-low enable  $\overline{G}$ , ground G and apply an inverted waveform  $\overline{G}$ .

Figure 4. Test Circuit and Voltage Waveforms,  $t_{\text{PZL}}$  and  $t_{\text{PLZ}}$ 

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
AM26LV31ESDREP	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 105	A26LV31ESP
AM26LV31ESDREP.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 105	A26LV31ESP
V62/09603-01XE	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 105	A26LV31ESP

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF AM26LV31E-EP:

Catalog : AM26LV31E

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

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NOTE: Qualified Version Definitions:

 $_{\bullet}$  Catalog - TI's standard catalog product

# D (R-PDS0-G16)

#### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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